| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|---|---|---|---|---|---|---|
| L1 | 2 | "6503846".pn. | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/31 16:37 |
| L2 | 180 | (oxynitride) with (high-k near dielectric) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/31 16:41 |
| L3 | 147 | (oxynitride) near15 (high-k near dielectric) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/31 16:41 |
| L4 | 26 | (oxynitride) near15 (high-k near dielectric) with (substrate or wafer) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/31 16:43 |
| L5 | 13 | (oxynitride) near15 (high-k near dielectric) with (electrode) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/31 16:45 |
| L6 | 13 | 5 and (substrate or wafer) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/31 16:46 |
| L7 | 0 | (oxy-nitride) near15 (high-k near dielectric) with (electrode) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/31 16:46 |
| L8 | 392 | (oxynitride) with (dielectric) with (electrode) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/31 16:46 |
| L9 | 378 | 8 and (substrate or wafer) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/31 16:46 |

| L10 | 50 | 9 and (high-k near dielectric) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/31 16:46 |
|---|---|---|---|---|---|---|
| L11 | 14 | 9 and (high-k near dielectric) with (electrode and oxynitride) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/31 16:47 |
| L12 | 50 | 9 and (high-k near dielectric) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/31 16:58 |
| L13 | 50 | 12 and (substrate or wafer) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/31 16:58 |
| L14 | 211 | 9 and (high near3 dielectric) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/31 16:58 |
| L15 | 211 | 14 and (substrate or wafer) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/31 16:58 |
| L16 | 176 | 15 and (oxynitride near15 electrode) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/31 16:59 |
| L17 | 176 | 16 and ((dielectric) near15 (electrode or oxynitride)) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/31 17:00 |
| L18 | 171 | 16 and ((dielectric) near15 (electrode and oxynitride)) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/31 17:00 |